

C3M0120090D Information


For Reference Only

Part Number [C3M0120090D](#)
Manufacturer Cree/Wolfspeed
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description 900V, 120 MOHM, G3 SIC MOSFET
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


[Request a Quote](#)
Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


C3M0120090D Specifications

Manufacturer Part Number	C3M0120090D
Manufacturer	Cree/Wolfspeed
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	C3M?
FET Type	N-Channel
Technology	SiCFET (Silicon Carbide)
Drain to Source Voltage (Vdss)	900V
Current - Continuous Drain (Id) @ 25°C	23A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	15V
Vgs(th) (Max) @ Id	3.5V @ 3mA
Gate Charge (Qg) (Max) @ Vgs	17.3nC @ 15V
Input Capacitance (Ciss) (Max) @ Vds	350pF @ 600V
Vgs (Max)	+18V, -8V
FET Feature	-
Power Dissipation (Max)	97W (Tc)
Rds On (Max) @ Id, Vgs	155 mOhm @ 15A, 15V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247-3
Package / Case	TO-247-3

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C3M0120090D Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

C3M0120090D Payment Methods



C3M0120090D Shipping Methods



If you have any question about C3M0120090D, please do not hesitate to contact us!

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